


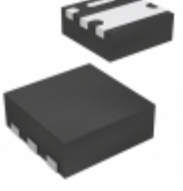


	<h2>SIA411DJ-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SIA411DJ-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 20V 12A SC70-6</p> <p>Datenblätter:  SIA411DJ-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 3509 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIA411DJ-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 20V 12A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	3509 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SC-70-6
Supplier Device-Gehäuse	PowerPAK® SC-70-6 Single
Verlustleistung (max)	3.5W (Ta), 19W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A (Tc)
Rds On (Max) @ Id, Vgs	30 mOhm @ 5.9A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	38nC @ 8V
Eingabekapazität (Ciss) (Max) @ Vds	1200pF @ 10V
Verpackung	Tape & Reel (TR)



















































SIA411DJ-T1-GE3 ist neu im Original. Suche SIA411DJ-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIA411DJ-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIA411DJ-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 SIA413DJ-T4-GE3 VISHAY SIA413DJ-T4-GE3 VISHAY	 SIA411DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 12A SC70-6	 SIA411DJ-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 12A SC70-6	 SIA413DJ-T1-E3 Vishay Precision Group SIA413DJ-T1-E3 VISHAY
 SIA411DJ-T1-E3 Vishay / Siliconix MOSFET P-CH 20V 12A SC70-6	 SIA413DJ-T1-GE3 Vishay / Siliconix MOSFET P-CH 12V 12A SC70-6	 SIA413DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 12V 12A SC70-6	 SIA408DJ-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 4.5A SC70-6

heiße Teile

Mehr

 SIA400EDJ-T1-GE3	 SIA400EDJ-T1-GE3	 SIA402DJ-T1-E3	 SIA406DJ-T1-GE3	 SIA406DJ-T1-GE3
 SIA408DJ-T1-GE3	 SIA408DJ-T1-GE3	 SIA411DJ-T1-GE3	 SIA413DJ-T1-GE3	 SIA413DJ-T1-GE3
 SIA413DJ-T4-GE3	 SIA414DJ-T1-GE3	 SIA414DJ-T1-GE3	 SIA415DJ-T1-GE3	 SIA415DJ-T1-GE3
 SIA417DJ-T1-GE3	 SIA417DJ-T1-GE3	 SIA419DJ	 SIA419DJ-T1-GE3	 SIA419DJ-T1-GE3
 SIA421DJ-T1-GE3	 SIA421DJ-T1-GE3	 SIA425EDJ-T1-GE3	 SIA425EDJ-T1-GE3	 SIA426DJ-T1-GE3
 SIA426DJ-T1-GE3	 SIA427DJ-T1-GE3	 SIA427DJ-T1-GE3	 SIA429DJ-T1-GE3	 SIA429DJ-T1-GE3
 SIA430DJ-T1-GE3	 SIA430DJ-T1-GE3	 SIA431DJ	 SIA431DJ-T1	 SIA431DJ-T1-GE3
 SIA431DJ-T1-GE3	 SIA432DJ-T1-GE3	 SIA432DJ-T1-GE3	 SIA433EDJ	 SIA433EDJ-T1-GE3
 SIA433EDJ-T1-GE3	 SIA436DJ-T1-GE3	 SIA436DJ-T1-GE3	 SIA443DJ-T1-GE3	 SIA443DJ-T1-GE3
 SIA444DJ-T1-GE3	 SIA444DJ-T1-GE3	 SIA445EDJ-T1-GE3	 SIA445EDJ-T1-GE3	 SIA447DJ-T1-GE3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited